

## **isc Silicon NPN RF Transistor**

# 2SC5772

#### DESCRIPTION

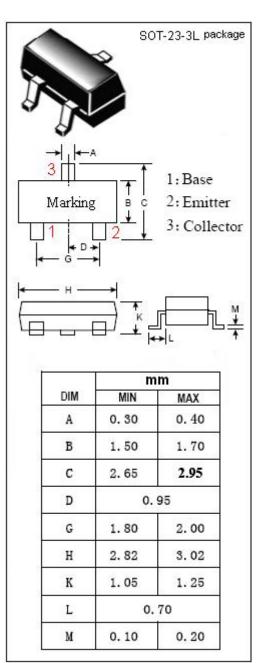
- High Gain Bandwidth Product
  - f<sub>T</sub> = 9 GHz TYP.
- High power gain and low noise figure ;
  - PG = 13 dB TYP., NF = 1.1 dB typ. @ f = 900 MHz
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

• Designed for use in UHF ~ VHF wide band amplifier.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>сво</sub>	Collector-Base Voltage	15	V			
V <sub>CEO</sub>	Collector-Emitter Voltage	9	V			
V <sub>EBO</sub>	Emitter-Base Voltage	1.5	V			
lc	Collector Current-Continuous	75	mA			
Pc	Collector Power Dissipation @Tc=25°C	0.7	W			
TJ	Junction Temperature	150	°C			
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C			

## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)



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## **ELECTRICAL CHARACTERISTICS**

## $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 10 μ A ; I <sub>E</sub> = 0	15			V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 12V; I <sub>E</sub> = 0			1	μA
I <sub>CEO</sub>	Collector Cutoff Current	$V_{CE}$ = 9V; $R_{BE}$ = $\infty$			1	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 1.5V; I <sub>C</sub> = 0			10	μ Α
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 20mA ; V <sub>CE</sub> = 5V	80		160	
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 20mA ; V <sub>CE</sub> = 5V ;f= 1 GHz	6	9		GHz
Сов	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 5V;f= 1.0MHz		0.9	1.5	pF
Cre	Reverse Transfer Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 5V;f= 1.0MHz		0.7		pF
S <sub>21e</sub>   <sup>2</sup>	Insertion Power Gain	Ic= 20mA ; Vce= 5V;f= 1GHz		11.8		dB
PG	Power Gain	I <sub>C</sub> = 20mA ; V <sub>CC</sub> = 5V;f= 900MHz	9.5	13		dB
NF	Noise Figure	Ic= 5mA ; Vcc= 5V;f= 900MHz		1.1	1.9	dB

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